

TRIAC(Through Hole / Non-isolated)

TMG25CQ60L

(Tj=150°C)

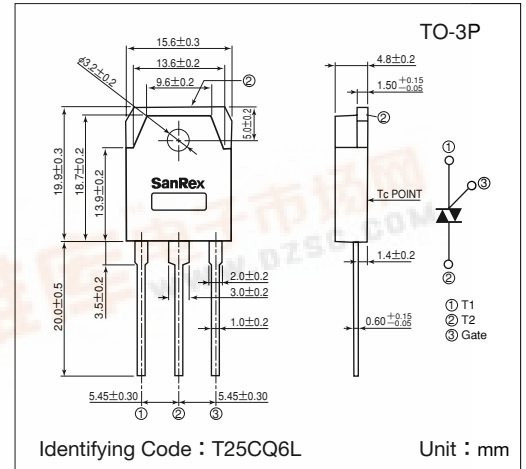
SanRex Triac **TMG25CQ60L** is designed for full wave AC control applications. It can be used as an ON/OFF function or for phase control operation.

Typical Applications

- Home Appliances : Washing Machines, Vacuum Cleaners, Rice Cookers, Micro Wave Ovens, Hair Dryers, other control applications
- Industrial Use : SMPS, Copier Machines, Motor Controls, Dimmer, SSR, Heater Controls, Vending Machines, other control applications

Features

- $I_{T(RMS)}=25A$
- High Surge Current
- Low Voltage Drop
- Lead-Free Package



Maximum Ratings

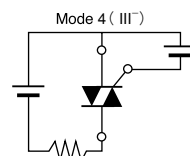
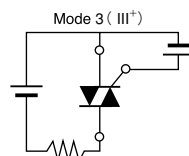
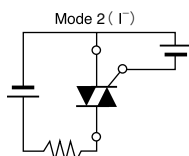
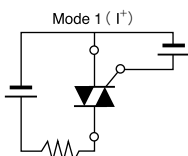
(Tj=25°C unless otherwise specified)

Symbol	Item	Reference	Ratings	Unit
V_{DRM}	Repetitive Peak Off-State Voltage		600	V
$I_{T(RMS)}$	R.M.S. On-State Current	$T_c=114^\circ C$	25	A
I_{TSM}	Surge On-State Current	One cycle, 50Hz/60Hz, Peak value non-repetitive	225/250	A
I^2t	I^2t (for fusing)		260	A ² S
P_{GM}	Peak Gate Power Dissipation		5	W
$P_{G(AV)}$	Average Gate Power Dissipation		0.5	W
I_{GM}	Peak Gate Current		2	A
V_{GM}	Peak Gate Voltage		10	V
T_j	Operating Junction Temperature		-40~+150	°C
T_{stg}	Storage Temperature		-40~+150	°C
	Mass		5.1	g

Electrical Characteristics

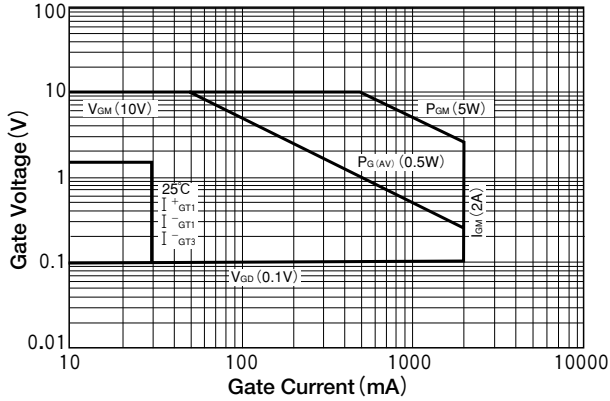
Symbol	Item		Reference	Ratings			Unit
				Min.	Typ.	Max.	
IDRM	Repetitive Peak Off-State Current		VD=VDRM, Single phase, half wave, Tj=150°C			5	mA
VTM	Peak On-State Voltage		It=35A, Inst. measurement			1.4	V
I_{GT1}^{+}	1	Gate Trigger Current	VD=6V, RL=10Ω			30	mA
I_{GT1}^{-}	2					30	
I_{GT3}^{+}	3					—	
I_{GT3}^{-}	4					30	
V_{GT1}^{+}	1	Gate Trigger Voltage				1.5	V
V_{GT1}^{-}	2					1.5	
V_{GT3}^{+}	3					—	
V_{GT3}^{-}	4					1.5	
VGD	Non-Trigger Gate Voltage		Tj=150°C, VD=1/2VDRM	0.1			V
(dv/dt)c	Critical Rate of Rise of Off-State Voltage at Commutation		Tj=150°C, [di/dt]c=−12.5A/ms, VD=2/3VDRM	5			V/μs
IH	Holding Current				35		mA
Rth	Thermal Resistance		Junction to case			1.2	°C/W

Trigger mode of the triac

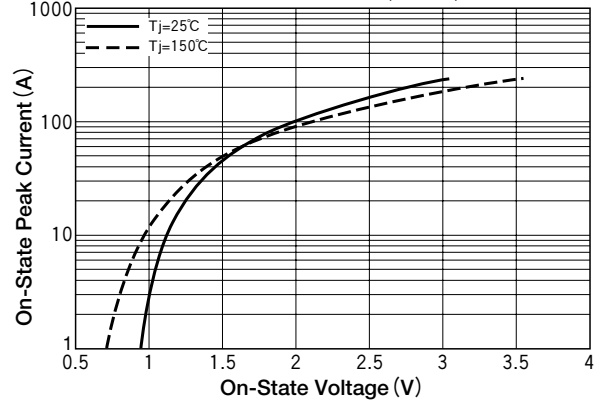


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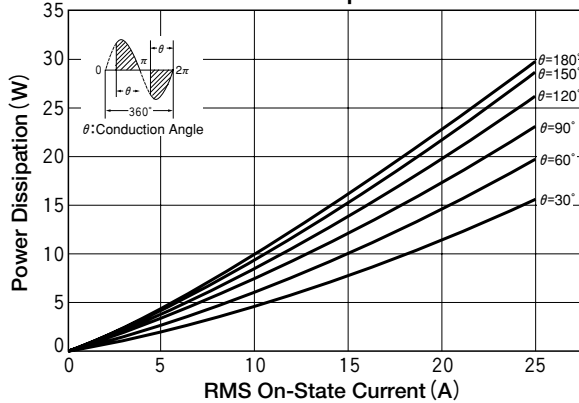
Gate Characteristics



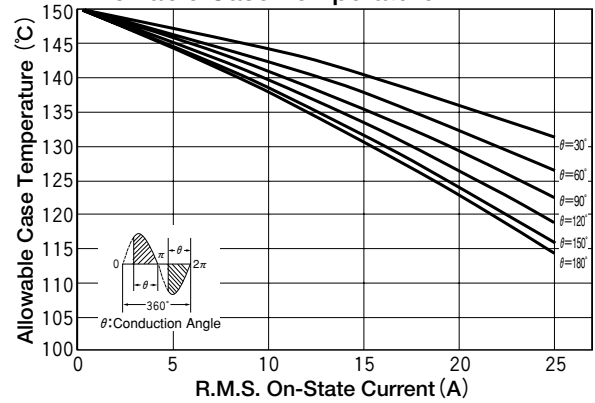
On-State Characteristics (MAX)



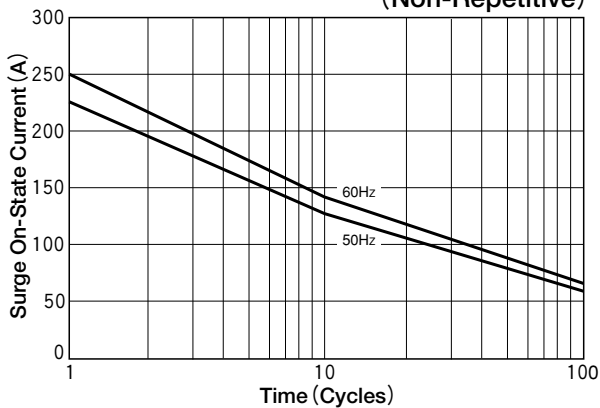
RMS On-State Current vs Maximum Power Dissipation



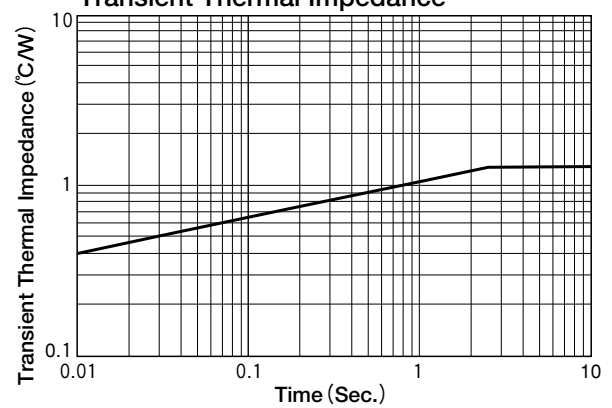
R.M.S On-State vs Allowable Case Temperature



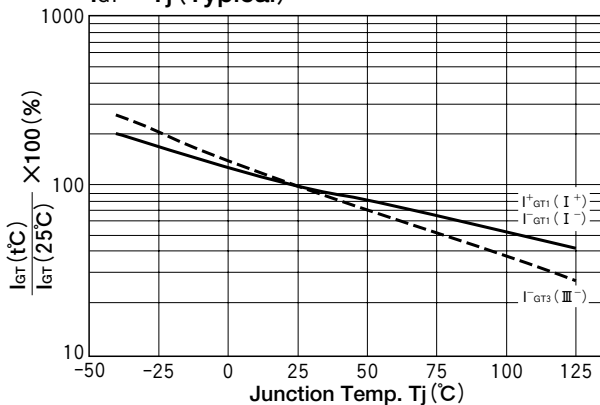
Surge On-State Current Rating (Non-Repetitive)



Transient Thermal Impedance



$I_{GT} - T_J$ (Typical)



$V_{GT} - T_J$ (Typical)

